



## CAN-Transceiver

**TLE 6250**

### Preliminary Data Sheet

#### Features

- CAN data transmission rate up to 1 MBaud
- Suitable for 12 V and 24 V applications
- Excellent EMC performance (very high immunity and very low emission)
- Version for 5 V and 3.3 V micro controllers
- Bus pins are short circuit proof to ground and battery voltage
- Over-temperature protection
- Very wide temperature range (- 40°C up to 150°C)



P-DSO-8-3

Type	Ordering Code	Package
TLE 6250 G	Q67006-A9427	P-DSO-8-3
TLE 6250 C	Q67000-A9520	(chip)
TLE 6250 G V33	Q67006-A9523	P-DSO-8-3
TLE 6250 C V33	Q67000-A9521	(chip)

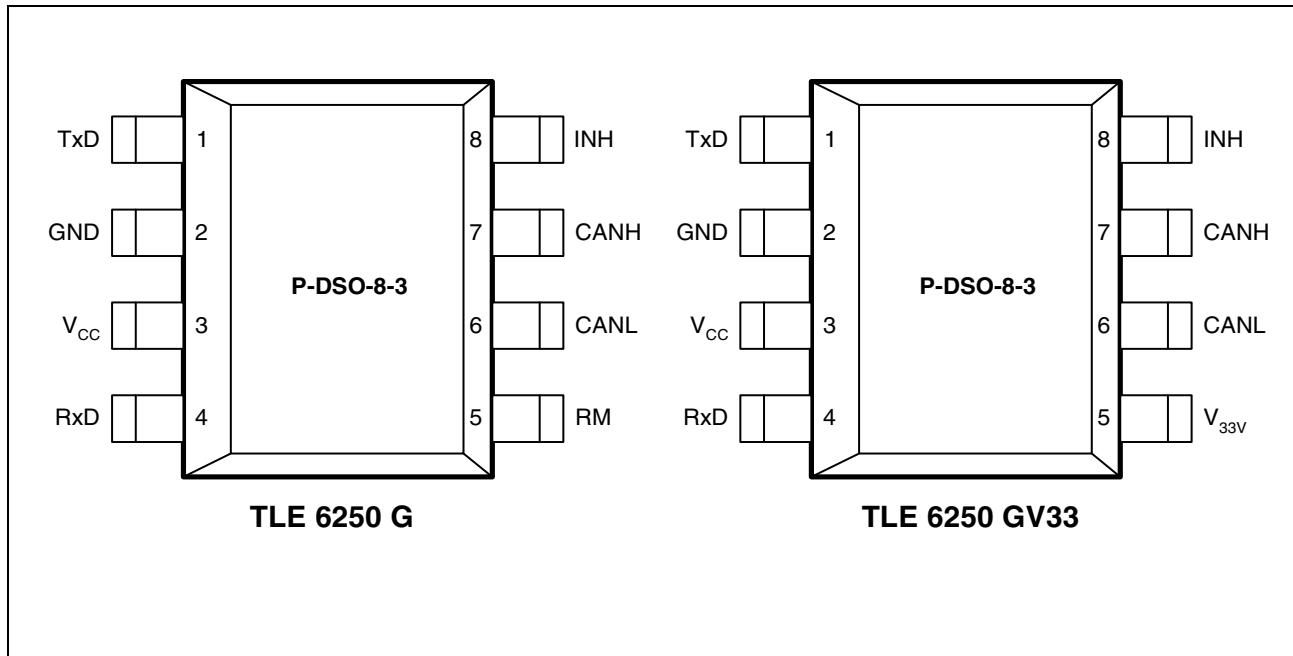
#### Description

The CAN-transceiver TLE 6250 is a monolithic integrated circuit that is available as bare die as well as in a P-DSO-8-3 package. The IC is optimized for high speed differential mode data transmission in automotive and industrial applications and is compatible to ISO/DIS 11898 (see page 10). It works as an interface between the CAN protocol controller and the physical differential bus in both, 12 V and 24 V systems.

There are two versions available: one for 5 V logic and the other one for 3.3 V logic requiring additional supply via the V<sub>33V</sub> pin. The IC can be set to stand-by mode via an control input. In addition the 5 V-version offers a receive only mode feature to support diagnostic functions.

The IC is based on the **Smart Power Technology SPT®** which allows bipolar and CMOS control circuitry in accordance with DMOS power devices existing on the same monolithic circuit.

The TLE 6250 is designed to withstand the severe conditions of automotive applications and provides excellent EMC performance.

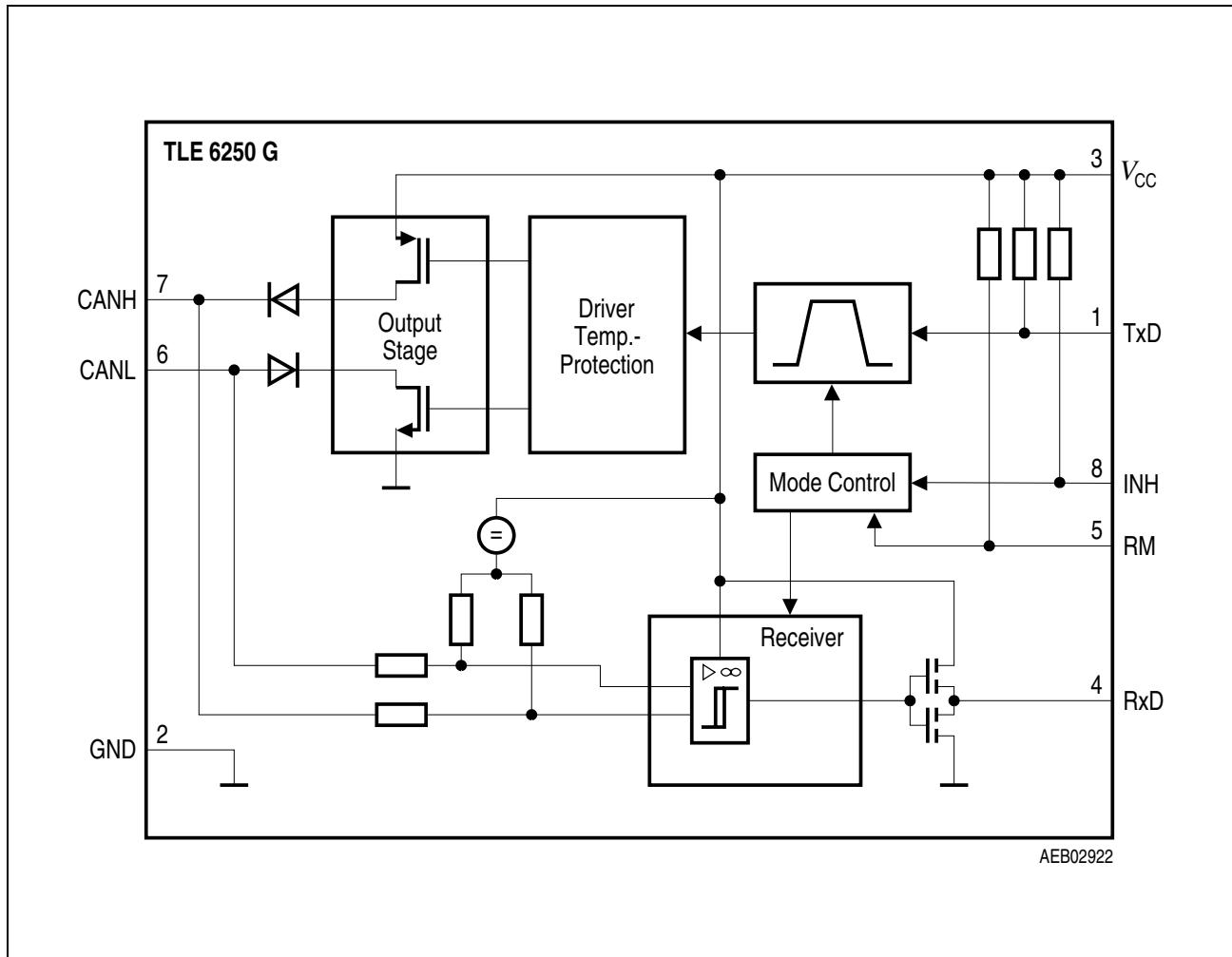


**Figure 1** Pin Configuration (top view)

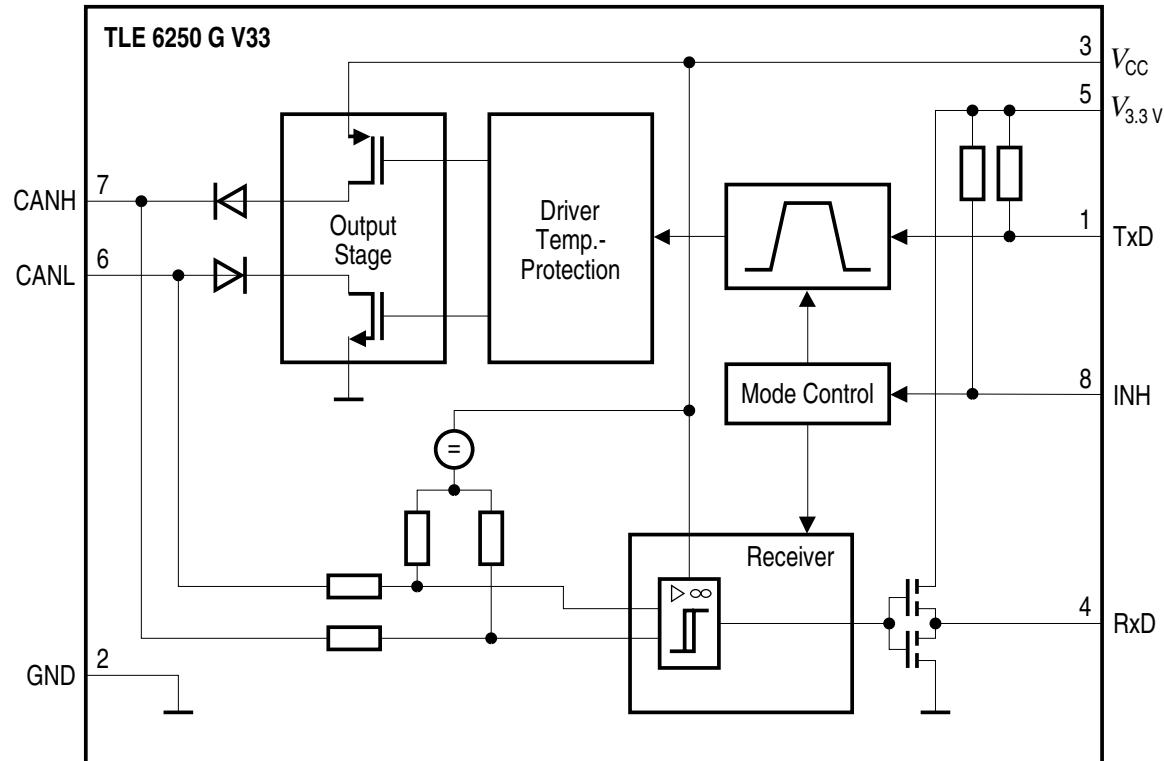
### Pin Definitions and Functions

Pin No.	Symbol	Function
1	TxD	<b>CAN transmit data input;</b> 20 kΩ pull up, LOW in dominant state
2	GND	<b>Ground;</b>
3	V <sub>cc</sub>	<b>5 V Supply;</b>
4	RxD	<b>CAN receive data output;</b> LOW in dominant state, integrated pull up
5	RM V <sub>33V</sub>	<b>Receive-only input;</b> (5 V-version), 20 kΩ pull up, set low to activate RxD-only mode <b>3.3 V logic supply;</b> (3.3 V-version) for applications using 3.3 V microcontroller
6	CANL	<b>Low line input;</b> LOW in dominant state
7	CANH	<b>High line output;</b> HIGH in dominant state
8	INH	<b>Control input;</b> 20 kΩ pull, set LOW for normal mode

## Functional Block Diagram



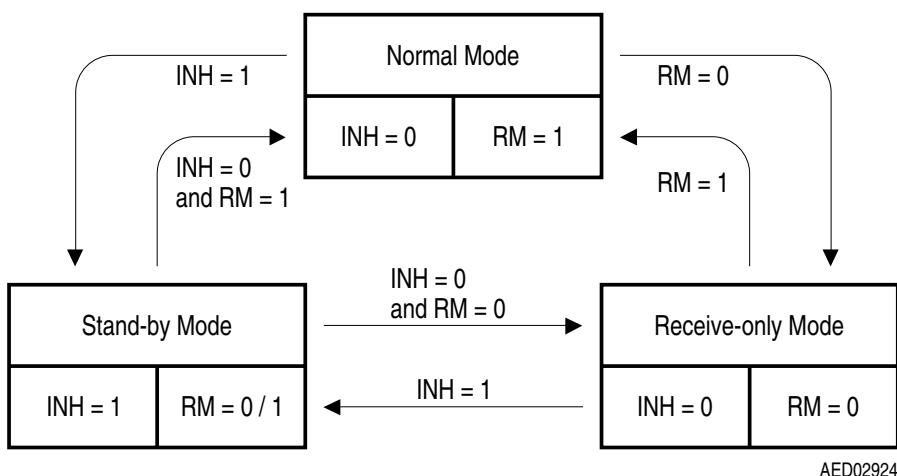
**Figure 2 Block Diagram TLE 6250 G**



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**Figure 3 Block Diagram TLE 6250 G V33**

## Application Information



**Figure 4 Mode State Diagram (5V version)**

Both, the TLE 6250 G as well as the TLE 6250 C offer three different operation modes (see **Figure 4**). In the normal mode the device is able to receive and to transmit messages whereas in the receive-only mode signals at the TxD input are not transmitted to the CAN bus. The receive-only mode can be used for diagnostic purposes as well as to prevent the bus being blocked by a faulty permanent dominant TxD input signal. The stand-by mode is a low power mode that disables both, the receiver as well as the transmit TLE 6250 G V33 and TLE 6250 C V33 the receive only mode feature is not available. The inhibit feature for this versions works in the same way as for the 5V versions.

In case the receive-only feature is not used the RM pin has to be left open. When the stand-by mode is not used the INH pin has to be connected to ground level in order to switch the TLE 6250 in normal mode.

## Electrical Characteristics

### Absolute Maximum Ratings

Parameter	Symbol	Limit Values		Unit	Remarks
		min.	max.		

### Voltages

Supply voltage	$V_{CC}$	- 0.3	6.5	V	-
3.3 V supply	$V_{33V}$	- 0.3	5.5	V	3.3 V version
CAN input voltage (CANH, CANL)	$V_{CANH/L}$	- 20	40	V	-
Logic voltages at INH, RM, TxD, RxD	$V_I$	- 0.3	$V_{CC}$	V	$0 \text{ V} < V_{CC} < 5.5 \text{ V}$
Electrostatic discharge voltage	$V_{ESD}$	- 2	2	kV	human body model (100 pF via 1.5 k $\Omega$ )

### Temperatures

Junction temperature	$T_j$	- 40	160	°C	-
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*Note: Maximum ratings are absolute ratings; exceeding any one of these values may cause irreversible damage to the integrated circuit.*

## Operating Range

Parameter	Symbol	Limit Values		Unit	Remarks
		min.	max.		
Supply voltage	$V_{CC}$	4.5	5.5	V	–
3 V supply voltage	$V_{33V}$	3.0	3.6	V	3.3 V-version
Junction temperature	$T_j$	– 40	150	°C	–

## Thermal Resistances

Junction ambient	$R_{thj-a}$	–	185	K/W	–
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## Thermal Shutdown (junction temperature)

Thermal shutdown temperature	$T_{jsD}$	160	200	°C	10 °C hysteresis
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## Electrical Characteristics

$4.5 \text{ V} < V_{CC} < 5.5 \text{ V}$ ; ( $3.0 \text{ V} < V_{33V} < 3.6 \text{ V}$  for 3.3 V version);  $R_L = 60 \Omega$ ;  $V_{INH} < V_{INH,ON}$ ;  $-40^\circ\text{C} < T_j < 150^\circ\text{C}$ ; all voltages with respect to ground; positive current flowing into pin; unless otherwise specified.

<b>Parameter</b>	<b>Symbol</b>	<b>Limit Values</b>			<b>Unit</b>	<b>Remarks</b>
		<b>min.</b>	<b>typ.</b>	<b>max.</b>		

## Current Consumption

Current consumption	$I_{CC}$	—	6	10	mA	recessive state; $V_{TxD} = V_{CC}$
Current consumption	$I_{CC}$	—	45	70	mA	dominant state; $V_{TxD} = 0 \text{ V}$
Current consumption	$I_{CC}$	—	6	10	mA	receive-only mode; RM = low
Current consumption	$I_{33V}$	—	—	2	mA	(3.3 V-version only)
Current consumption	$I_{CC,stb}$	—	1	10	$\mu\text{A}$	stand-by mode; TxD = RM = high
Current consumption	$I_{CC+33V,stb}$	—	1	10	$\mu\text{A}$	stand-by mode TxD = high (3.3 V-version only)

## Receiver Output RxD

HIGH level output current	$I_{RD,H}$	—	-4	-2	mA	$V_{RD} = 0.8 \times V_{CC}$ , $V_{diff} < 0.4 \text{ V}^{\text{note 1)}}$
		—	-1	—	mA	3.3 V-version $V_{RD} = 0.8 \times V_{33V}$ , $V_{diff} < 0.4 \text{ V}^{\text{note 1)}}$
LOW level output current	$I_{RD,L}$	2	4	—	mA	$V_{RD} = 0.2 \times V_{CC}$ , $V_{diff} > 1 \text{ V}^{\text{note 1)}}$
		1	2	—	mA	3.3 V-version $V_{RD} = 0.2 \times V_{33V}$ , $V_{diff} > 1 \text{ V}^{\text{note 1)}}$

note1)  $V_{diff} = V_{CANH} - V_{CANL}$

### Electrical Characteristics (cont'd)

$4.5 \text{ V} < V_{\text{CC}} < 5.5 \text{ V}$ ; ( $3.0 \text{ V} < V_{33\text{V}} < 3.6 \text{ V}$  for  $3.3 \text{ V}$  version);  $R_L = 60 \Omega$ ;  $V_{\text{INH}} < V_{\text{INH,ON}}$ ;  $-40^\circ\text{C} < T_j < 150^\circ\text{C}$ ; all voltages with respect to ground; positive current flowing into pin; unless otherwise specified.

<b>Parameter</b>	<b>Symbol</b>	<b>Limit Values</b>			<b>Unit</b>	<b>Remarks</b>
		<b>min.</b>	<b>typ.</b>	<b>max.</b>		

### Bus Receiver

Differential receiver threshold voltage, recessive to dominant edge	$V_{\text{diff,d}}$	—	0.75	0.90	V	$-20 \text{ V} < (V_{\text{CANH}}, V_{\text{CANL}}) < 25 \text{ V}$ $V_{\text{diff}} = V_{\text{CANH}} - V_{\text{CANL}}$
Differential receiver threshold voltage dominant to recessive edge	$V_{\text{diff,r}}$	0.50	0.60	—	V	$-20 \text{ V} < (V_{\text{CANH}}, V_{\text{CANL}}) < 25 \text{ V}$ $V_{\text{diff}} = V_{\text{CANH}} - V_{\text{CANL}}$
Differential receiver hysteresis	$V_{\text{diff,hys}}$	—	150	—	mV	—
CANH, CANL input resistance	$R_i$	—	20	—	kΩ	recessive state
Differential input resistance	$R_{\text{diff}}$	—	40	—	kΩ	recessive state

### Transmission Input TxD

HIGH level input voltage threshold	$V_{\text{TD,H}}$	—	2.5	3.5	V	recessive state; 5.0 V-version
		—	1.6	2.4	V	recessive state; 3.3 V-version
TxD input hysteresis	$V_{\text{TD,hys}}$	0.1	0.5	1	V	—
LOW level input voltage threshold	$V_{\text{TD,L}}$	1.5	2.0	—	V	dominant state
		0.9	1.5	—	V	dominant state 3.3 V-version
TxD pull up resistance	$R_{\text{TD}}$	10	25	50	kΩ	—

### Electrical Characteristics (cont'd)

$4.5 \text{ V} < V_{\text{CC}} < 5.5 \text{ V}$ ; ( $3.0 \text{ V} < V_{33\text{V}} < 3.6 \text{ V}$  for 3.3 V version);  $R_L = 60 \Omega$ ;  $V_{\text{INH}} < V_{\text{INH,ON}}$ ;  $-40^\circ\text{C} < T_j < 150^\circ\text{C}$ ; all voltages with respect to ground; positive current flowing into pin; unless otherwise specified.

<b>Parameter</b>	<b>Symbol</b>	<b>Limit Values</b>			<b>Unit</b>	<b>Remarks</b>
		<b>min.</b>	<b>typ.</b>	<b>max.</b>		

### Bus Transmitter

CANL/CANH recessive output voltage	$V_{\text{CANL/H}}$	$0.4 \times V_{\text{CC}}$	—	$0.6 \times V_{\text{CC}}$	V	$V_{\text{TxD}} = V_{\text{CC}}$ (5 V-version) $V_{\text{TxD}} = V_{33\text{V}}$ (3.3 V-version)
CANH, CANL recessive output voltage difference $V_{\text{diff}} = V_{\text{CANH}} - V_{\text{CANL}}$	$V_{\text{diff}}$	- 1	—	0.05	V	$V_{\text{TxD}} = V_{\text{CC}}$ (5 V-version) $V_{\text{TxD}} = V_{33\text{V}}$ (3.3 V-version); no load; (see note 2)
CANL dominant output voltage	$V_{\text{CANL}}$	—	—	2.0	V	$V_{\text{TxD}} = 0 \text{ V}$ ; $V_{\text{CC}} = 5 \text{ V}$
CANH dominant output voltage	$V_{\text{CANH}}$	2.8	—	—	V	$V_{\text{TxD}} = 0 \text{ V}$ ; $V_{\text{CC}} = 5 \text{ V}$
CANH, CANL dominant output voltage difference $V_{\text{diff}} = V_{\text{CANH}} - V_{\text{CANL}}$	$V_{\text{diff}}$	1.5	—	3.0	V	$V_{\text{TxD}} = 0 \text{ V}$ ; $V_{\text{CC}} = 5 \text{ V}$
CANL short circuit current	$I_{\text{CANLsc}}$	50	120	200	mA	$V_{\text{CANLshort}} = 18 \text{ V}$
		—	150	—	mA	$V_{\text{CANLshort}} = 36 \text{ V}$
CANH short circuit current	$I_{\text{CANHsc}}$	-200	-120	-50	mA	$V_{\text{CANHshort}} = 0 \text{ V}$
CANH short circuit current	$I_{\text{CANHsc}}$	—	-120	—	mA	$V_{\text{CANHshort}} = -5 \text{ V}$
Output current	$I_{\text{CANH,ik}}$ $I_{\text{CANL,ik}}$	—	-300	—	$\mu\text{A}$	$V_{\text{CC}} = 0 \text{ V}$ , $V_{\text{CANH}} = V_{\text{CANL}} = -7 \text{ V}$
Output current	$I_{\text{CANH,ik}}$ $I_{\text{CANL,ik}}$	—	280	—	$\mu\text{A}$	$V_{\text{CC}} = 0 \text{ V}$ , $V_{\text{CANH}} = V_{\text{CANL}} = 7 \text{ V}$

note 2) deviation from ISO/DIS 11898

### **Electrical Characteristics (cont'd)**

$4.5 \text{ V} < V_{CC} < 5.5 \text{ V}$ ; ( $3.0 \text{ V} < V_{33V} < 3.6 \text{ V}$  for  $3.3 \text{ V}$  version);  $R_L = 60 \Omega$ ;  $V_{INH} < V_{INH,ON}$ ;  $-40^\circ\text{C} < T_j < 150^\circ\text{C}$ ; all voltages with respect to ground; positive current flowing into pin; unless otherwise specified.

<b>Parameter</b>	<b>Symbol</b>	<b>Limit Values</b>			<b>Unit</b>	<b>Remarks</b>
		<b>min.</b>	<b>typ.</b>	<b>max.</b>		

### **Inhibit Input (pin INH)**

HIGH level input voltage threshold	$V_{INH,H}$	–	2.5	3.5	V	stand-by mode; 5.0 V-version
		–	1.6	2.4	V	stand-by mode; 3.3 V-version
LOW level input voltage threshold	$V_{INH,L}$	1.5	2.0	–	V	normal mode
		0.9	1.5	–	V	normal mode; 3.3 V-version
INH pull up resistance	$R_{INH}$	10	25	50	kΩ	–

### **Receive only Input (RM)**

HIGH level input voltage threshold	$V_{RM,H}$	–	2.5	3.5	V	normal mode; 5.0 V-version
LOW level input voltage threshold	$V_{RM,L}$	1.5	2.0	–	V	receive-only mode
RM pull up resistance	$R_{RM}$	10	25	50	kΩ	–

### Electrical Characteristics (cont'd)

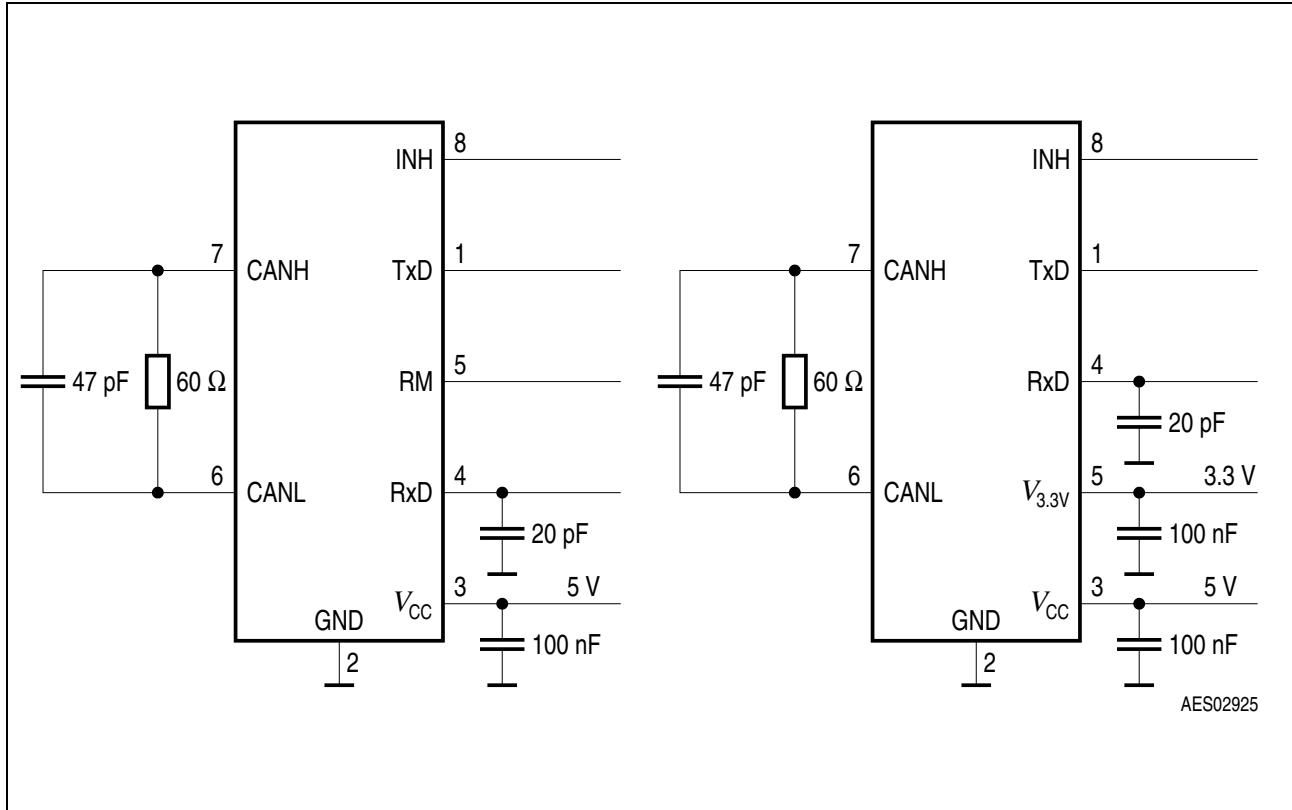
$4.5 \text{ V} < V_{\text{CC}} < 5.5 \text{ V}$ ; ( $3.0 \text{ V} < V_{\text{33V}} < 3.6 \text{ V}$  for  $3.3 \text{ V}$  version);  $R_L = 60 \Omega$ ;  $V_{\text{INH}} < V_{\text{INH,ON}}$ ;  $-40^\circ\text{C} < T_j < 150^\circ\text{C}$ ; all voltages with respect to ground; positive current flowing into pin; unless otherwise specified.

<b>Parameter</b>	<b>Symbol</b>	<b>Limit Values</b>			<b>Unit</b>	<b>Remarks</b>
		<b>min.</b>	<b>typ.</b>	<b>max.</b>		

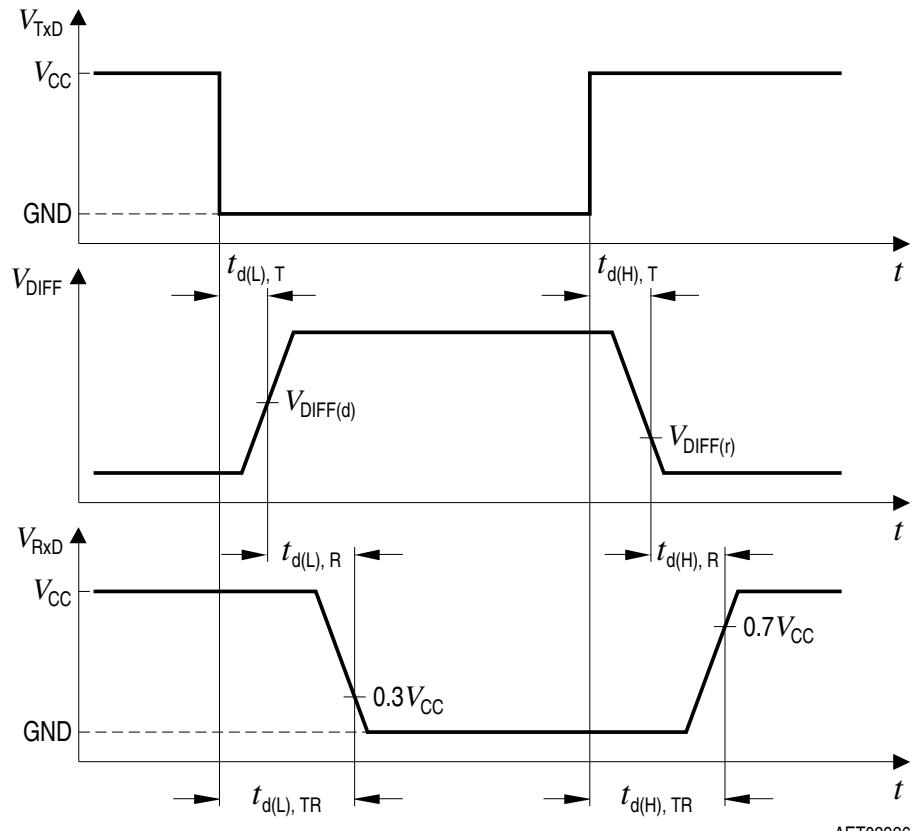
### Dynamic CAN-Transceiver Characteristics

Propagation delay TxD-to-RxD LOW (recessive to dominant)	$t_{d(L),TR}$	—	150	280	ns	$C_L = 47 \text{ pF};$ $R_L = 60 \Omega$ ; $V_{\text{CC}} = 5 \text{ V}$ ; $C_{\text{RxD}} = 20 \text{ pF}$
Propagation delay TxD-to-RxD HIGH (dominant to recessive)	$t_{d(H),TR}$	—	150	280	ns	$C_L = 47 \text{ pF};$ $R_L = 60 \Omega$ ; $V_{\text{CC}} = 5 \text{ V}$ ; $C_{\text{RxD}} = 20 \text{ pF}$
Propagation delay TxD LOW to bus dominant	$t_{d(L),T}$	—	100	—	ns	$C_L = 47 \text{ pF};$ $R_L = 60 \Omega$ ; $V_{\text{CC}} = 5 \text{ V}$
Propagation delay TxD HIGH to bus recessive	$t_{d(H),T}$	—	100	—	ns	$C_L = 47 \text{ pF};$ $R_L = 60 \Omega$ ; $V_{\text{CC}} = 5 \text{ V}$
Propagation delay bus dominant to RxD LOW	$t_{d(L),R}$	—	50	—	ns	$C_L = 47 \text{ pF};$ $R_L = 60 \Omega$ ; $V_{\text{CC}} = 5 \text{ V}$ ; $C_{\text{RxD}} = 20 \text{ pF}$
Propagation delay bus recessive to RxD HIGH	$t_{d(H),R}$	—	50	—	ns	$C_L = 47 \text{ pF};$ $R_L = 60 \Omega$ ; $V_{\text{CC}} = 5 \text{ V}$ ; $C_{\text{RxD}} = 20 \text{ pF}$

## Diagrams

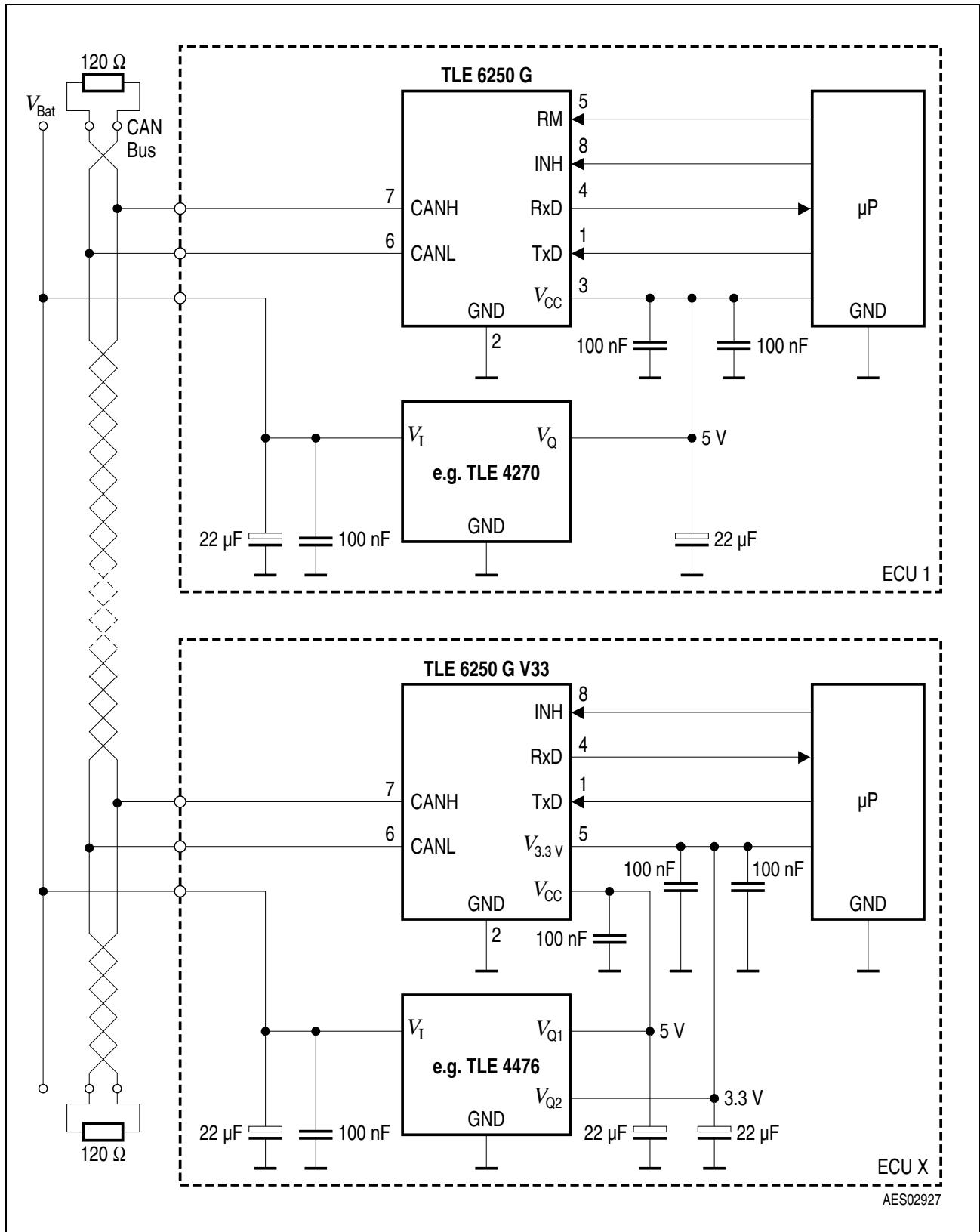


**Figure 5      Test Circuits for Dynamic Characteristics**



**Figure 6      Timing Diagrams for Dynamic Characteristics**

## Application

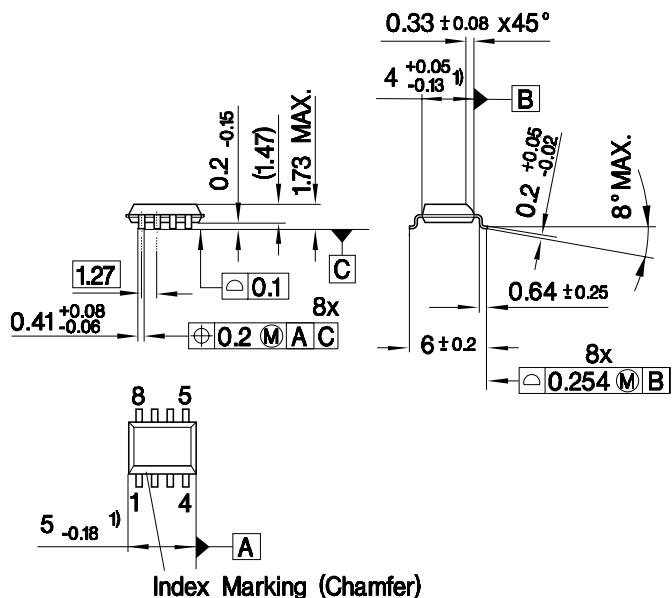


**Figure 7 Application Circuit**

## Package Outlines

P-DSO-8-3

(Plastic Dual Small Outline Package)



1) Does not include plastic or metal protrusion of 0.15 max. per side

GPS09032

## **Sorts of Packing**

**Certs of Packing**  
Package outlines for tubes, trays etc. are contained in our Data Book "Package Information"

## SMD = Surface Mounted Device

Dimensions in mm

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Edition 2000-12-20

Published by Infineon Technologies AG,  
St.-Martin-Strasse 53,  
D-81541 München, Germany

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